

HT-03-038

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October 20, 2004

To: Commissioner for Patents

P.O. Box 1450

Alexandria, VA 22313-1450

Attn: Art Unit 2812 - Jennifer M. Kennedy

From: George O. Saile, Reg. No. 19,572

28 Davis Avenue

Poughkeepsie, N. Y., 12603

Subject: | Serial No.: 10/849,311 05/19/04 |

Liubo Hong et al.

MRAM CELL STRUCTURE AND METHOD OF  
FABRICATION

|\_ Art Group: 2812 Jennifer M. Kennedy |

RESPONSE TO RESTRICTION REQUIREMENT

This is in response to the Restriction or Election Requirement in the Office Action dated 09/30/04. In that Office Action, restriction was required to one of two stated

CERTIFICATE OF MAILING

I hereby certify that this correspondence is being deposited with the United States Postal Service as first class mail in an envelope addressed to: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450, on October 21, 2004.

Stephen B. Ackerman, Reg.# 37761

Signature/Date

10/21/04

Inventions under 35 U.S.C. 121. The Inventions stated are Group I - Claims 1-24 to a process, classified in Class 438, subclass 3+ and Group II - Claims 25-39 to a semiconductor device, classified in Class 257, subclass 295+.

Applicant provisionally elects to be examined the Invention described by the Examiner as Group I - Claims 1-24 drawn to a process classified in Class 438, subclass 3+. This election is made with traverse of the requirement under 37 C.F.R.1.143 for the reasons given in the following paragraphs.

The Examiner is respectfully requested to reconsider the Requirement for Restriction given in the Office Action. The Examiner gives the reason for the distinctness of the two inventions as (1) that the process as claimed can be used to make other and materially different products or (2) that the product as claimed can be made by another and materially different process (MPEP 806.05(f)). However, upon reading the product Claims against the process Claims one can readily see that the product Claims are directed to "an MRAM cell structure formed on a substrate" and the process Claims are directed to "a method for planarizing an MRAM cell structure on an MRAM chip having an insulation layer with an uneven top surface formed on an MTJ which is comprised of a bottom layer on a substrate, a free layer on the bottom layer, and a cap layer on the free layer", it is necessary to obtain claims in both the

product and method claim language. The method Claims necessarily use the product and vice versa. The field of search must necessarily cover both the method class/subclass 438/3+ and products class 257/295+ in addition to other related Classes and subclasses to provide a complete and adequate search. The fields of search for the Group I and Group II inventions are clearly and necessarily co-extensive. The Examiner's suggestion that "In the instant case the device can be made by a different process such as etching back without the step of performing CMP", is very speculative and really has nothing to do with the Claims as presented in this Patent Application. Further, it is respectfully suggested that these reasons are insufficient to place the additional cost of a second Patent Application upon the Applicants. Therefore, it is respectfully requested that the Examiner withdraw this restriction requirement for these reasons.

Withdrawal of the Restriction Requirement and the Allowance of the present Patent Application is requested.

Sincerely,



Stephen B. Ackerman, Reg.# 37761